

Power-up Trouble Shooting

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INTRODUCTION

For any application to begin proper operation, the application must power-up properly. Many criteria must be taken into account to ensure this. The PICmicro™ devices integrate several features to simplify the design for the power-up sequence. These integrated features also reduce the total system cost.

This application note describes the requirements for the device to properly power-up, common pitfalls that designers encounter, and methods to assist in solving power-up problems.

THE POWER-UP SEQUENCE

There are several factors that determine the actual power-up sequence that a device will go through. These factors are:

- The Processor Family
 - PIC16C5X (Baseline)
 - PIC16CXXX (Midrange)
 - PIC17CXXX (High-end)
- Oscillator Configuration
- Device Configuration
- MCLR pin

Note: The PIC16CXXX family refers to devices with a 14-bit instruction word. This does not include the PIC16C5X family.

The Power-on Reset (POR) signal generation is discussed, followed by the power-up sequence for the specific device families.

Power-on Reset (POR) signal

The data sheets show a Power-on Reset (POR) pulse, as in Figure 1. The POR signal is a level triggered signal. This representation may help in the understanding of future devices, which may have a brown-out reset capability.

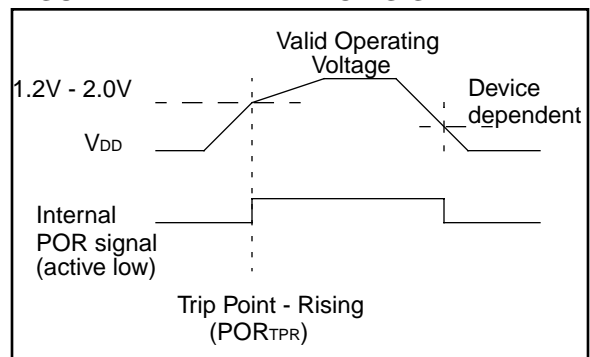
The power-up sequence begins by increasing the voltage on the V_{DD} pin (from 0V). If the slope of the V_{DD} rise time is faster than 0.05 V/ms, the internal circuitry is

capable of generating an internal reset signal. Depending on the device family, different power-up sequences will occur after this POR signal.

If the slope is less than 0.05 V/ms, the \overline{MCLR} pin should be held low, by external circuitry, until a valid operating V_{DD} level is reached.

The V_{DD} rise time specification needs to be met, until the POR signal is generated. After the POR signal is generated the slope of the V_{DD} rise can change (to a faster or slower rise). This may have other ramifications, see the "Power-up Consideration" section. In general, the POR signal will trip (POR_{TPR}) somewhere between 1.2V to 2.0V (Figure 1).

FIGURE 1: INTERNAL POR SIGNAL



When V_{DD} is falling, the voltage at which the internal POR signal returns to a low level is processor/device dependent. To ensure that a device will have a POR, the device voltage must return to V_{SS} before power is re-applied.

Note: Some devices (with EPROM program memory) have a newer POR circuit that does not require V_{DD} to return to V_{SS} . See the device data sheet for the complete specification on the POR operation.

The POR will be generated regardless of the level of the \overline{MCLR} pin. The PICmicro device families are different on what triggers the power-up sequence. Table 1 describes the events that cause the POR sequence to occur.

After reaching the POR trip point (POR_{TPR}), the POR sequence holds the device in reset for a given time. Once this time has elapsed, the device voltage must be valid or the \overline{MCLR} pin must be low. The time from the POR rising edge to the time that V_{DD} must be valid level is the $T_{POR2VDDV}$ time.

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TABLE 1: EVENTS THAT TRIGGER POR SEQUENCE

Device	Events
PIC16C5X	Both the POR signal rising edge and any $\overline{\text{MCLR}}$ rising edge ⁽¹⁾
PIC16CXXX	The POR signal rising edge
PIC17CXXX	Either the POR signal rising edge or the first $\overline{\text{MCLR}}$ rising edge (if $\overline{\text{MCLR}}$ is low when the POR occurs). After this event, all following $\overline{\text{MCLR}}$ rising edges ⁽¹⁾ cause the device to start program execution immediately.

Note 1: The POR low-to-high transition configures Special Function Register (SFR) bits/registers to a specified value. The SFR bits/register are not identically affected by the $\overline{\text{MCLR}}$ signal. Refer to the device data sheet to see how the bits are affected by these two conditions.

The POR sequence for each of the PICmicro families is described in the following three sections:

- PIC16C5X Family
- PIC16CXXX Family
- PIC17CXXX Family

PIC16C5X Family

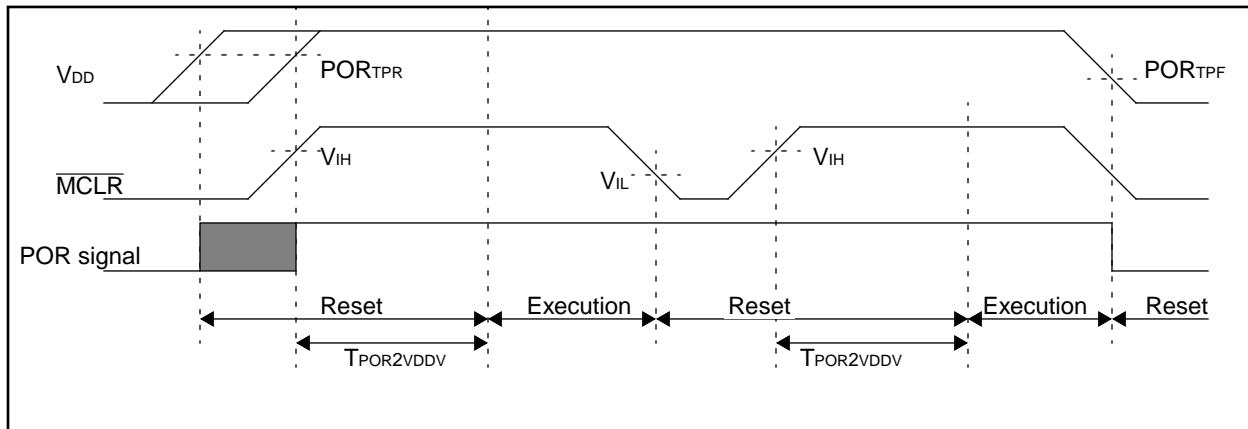
After the $\overline{\text{MCLR}}$ pin has reached a high level, the device is held in reset for typically 18 ms. This time is determined by an on-chip RC oscillator and 8-bit ripple counter. This Device Reset Timer (DRT), allows most crystals (except low frequency crystals) to start-up and stabilize. Due to the characteristics of resistors and capacitors, this time is extremely variable over temperature and voltage. There is also a device to device variation. See the data sheet for the range of this time-out.

TABLE 2: TIME-OUT IN VARIOUS SITUATIONS (TYPICAL)

Oscillator Configuration	Power-up	Wake-up from SLEEP
XT, HS, LP ⁽¹⁾	18 ms	18 ms
RC	18 ms	18 ms

Note 1: 32 kHz crystals have a typical start-up time of 1-2 seconds. Crystals >100 kHz have a typical start-up time of 10-20 ms. Resonators are typically <1 ms. All these times are voltage dependent.

FIGURE 2: PIC16C5X POWER-UP SEQUENCE



PIC16CXXX Family

After the POR rising edge has occurred, the device can have up to 2 time-out sequences that occur in series. The first being the Power-up Timer (PWRT), the second being the Oscillator Start-up Timer (OST).

The Power-up Timer time-out will occur if enable bit PWRTE is read as a '1'. The PWRT uses a 10-bit counter, with the clock from an internal RC. Due to the characteristics of resistors and capacitors, this time is extremely variable over temperature and voltage. There is also a device to device variation. See the data sheet for the range of this time-out.

Note: Future devices will change the polarity of the PWRTE configuration bit. Refer to the specific data sheet for the polarity of this bit.

The OST will occur on power-up/wake-up when the device has oscillator mode selected. This allows the oscillator to stabilize before program execution begins. The OST uses a 10-bit counter, with the clock from the OSC pin. The time is dependent on the frequency of the input clock. This timer is disabled if the oscillator is configured as RC.

Figure 3 shows how the two timers work in the power-up sequence. V_{DD} must be valid when program execution starts. The $T_{PWRT} + T_{OST}$ times can be thought of as the time that the device gives for the V_{DD} to become valid ($T_{POR2VDDV}$). Figure 4 shows when device execution begins for the case of the MCLR pin going high before $T_{POR2VDDV}$ times out. Figure 5 shows when the MCLR pin is held low longer than the $T_{POR2VDDV}$ time. The device starts execution immediately when MCLR goes high. Table 3 gives typical reset times.

TABLE 3: TIME-OUT IN VARIOUS SITUATIONS (TYPICAL)

Oscillator Configuration	Power-up		Wake-up from SLEEP
	PWRTE = 1 (2)	PWRTE = 0 (2)	
XT, HS, LP ⁽¹⁾	72 ms + 1024 T_{osc}	1024 T_{osc}	1024 T_{osc}
RC	72 ms	—	—

Note 1: 32 kHz crystals have a typical start-up time of 1-2 seconds. Crystals >100 kHz have a typical start-up time of 10-20 ms. Resonators are typically <1 ms. All these times are voltage dependent.

Note 2: Future devices will change the polarity of this configuration bit. Refer to the specific data sheet for the polarity of the PWRTE Configuration Bit.

FIGURE 3: PIC16CXX POWER-UP SEQUENCE

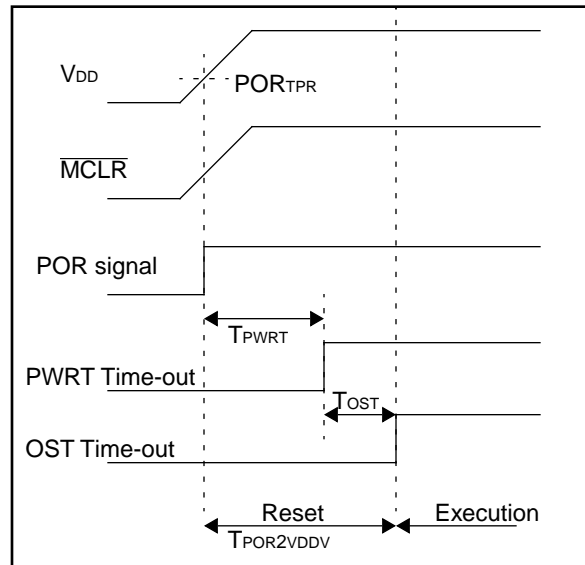


FIGURE 4: START OF DEVICE OPERATION (MCLR $T_{POR2VDDV}$)

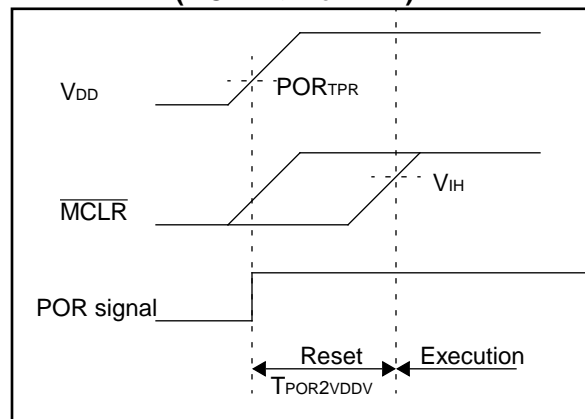
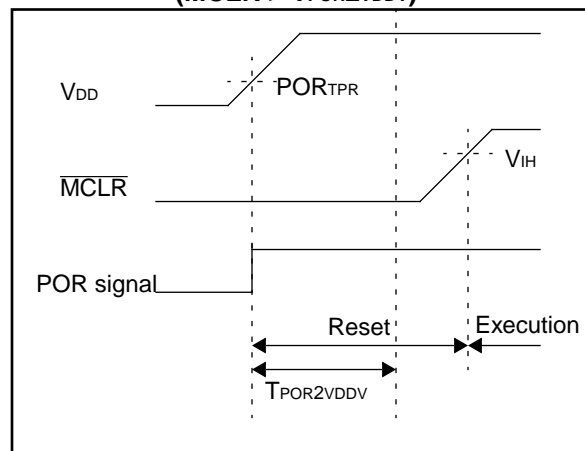


FIGURE 5: START OF DEVICE OPERATION (MCLR >math>T_{POR2VDDV}</math>)



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PIC17CXXX Family

When the $\overline{\text{MCLR}}$ pin comes to a high level, after the POR rising edge, the device has 2 time-out sequences that occur in parallel. One is the Power-up Timer (PWRT), the other is the Oscillator Start-up Timer (OST). The timer with the greater time holds the device in reset. Figure 6 shows the sequence with $\overline{\text{MCLR}}$ tied to V_{DD} . Figure 7 shows the time-out when $\overline{\text{MCLR}}$ is independent of V_{DD} . The PWRT time is generally longer, except for low frequency crystals/resonators. The OST time does not include the start-up time of the oscillator/resonator.

The PWRT uses a 10-bit counter, with the clock from an internal RC. The characteristics of the RC vary from device to device and over temperature and voltage. The specification for the time-out range can be found in the electrical specification of the data sheet.

The OST uses a 10-bit counter, with the clock from the OSC pin. The time is dependent on the frequency of the input clock.

Until $\overline{\text{MCLR}}$ has reached a high level, the POR sequence will not start. While the POR signal remains high, all following $\overline{\text{MCLR}}$ pulses will not cause the POR sequences to occur (Figure 8).

TABLE 4: TIME-OUT IN VARIOUS SITUATIONS (TYPICAL)

Oscillator Configuration	Power-up	Wake-up from Sleep
RC, EC	Greater of 80 ms and $1024 T_{osc}$	—
XT, LF ⁽¹⁾	Greater of 80 ms and $1024 T_{osc}$	$1024 T_{osc}$

Note 1: 32 kHz crystals have a typical start-up time of 1-2 seconds. Crystals >100 kHz have a typical start-up time of 10-20 ms. Resonators are typically <1 ms. All these times are voltage dependent.

FIGURE 6: PIC17CXX POWER-UP SEQUENCE ($\overline{\text{MCLR}}$ TIED TO V_{DD})

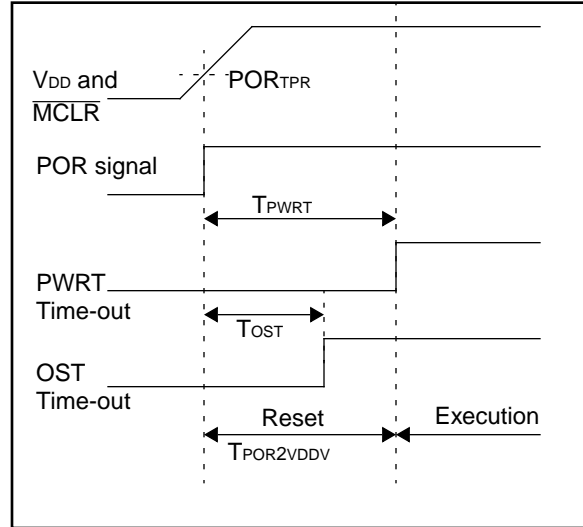


FIGURE 7: PIC17CXX POWER-UP SEQUENCE ($\overline{\text{MCLR}}$ NOT TIED TO V_{DD})

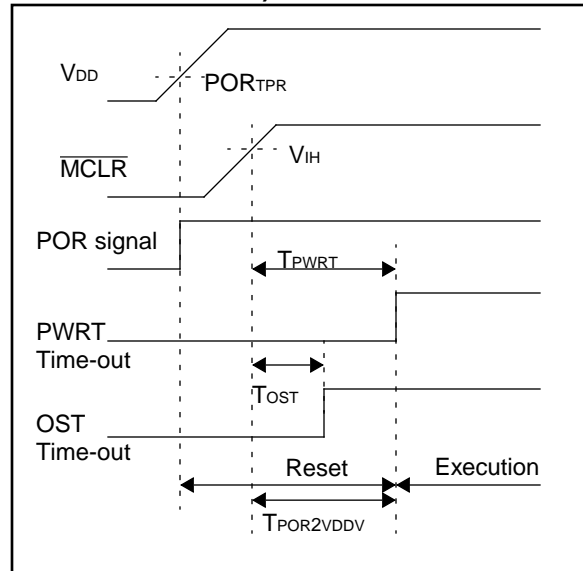
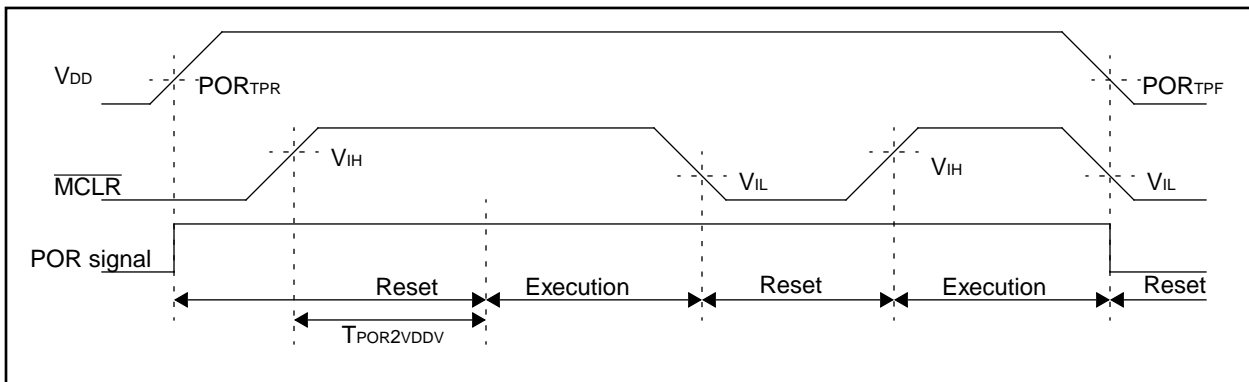


FIGURE 8: $\overline{\text{MCLR}}$ OPERATION



POWER-UP CONSIDERATIONS

The device must be at a valid operating voltage when the device exits reset. This can be done by ensuring that the power supply rise time is fast enough to guarantee an operating V_{DD} level, or by using an external reset circuit which will hold \overline{MCLR} low until the operating V_{DD} level is reached.

When the rise time of V_{DD} is very fast, there will be a time delay before the Power-on Reset (POR) signal will rise to a logic high ($T_{TP2PORH}$). This delay is in the 1-5 μs range, as shown in Figure 9.

Figure 10, Figure 11, and Figure 12 show the maximum time from the POR sequence beginning to the device having a valid operating voltage. Table 5 gives the $T_{POR2VDDV}$ times. When determining the time at which V_{DD} must be valid, the POR trip point must be assumed to be at the minimum POR voltage trip point.

How Crystal Frequencies affect Start-up time

Both the PIC16CXXX and PIC17CXXX families may have start-up times that include the contributions of the oscillator. Table 5 shows how the oscillator can affect each mode of operation, with Table 6 giving the reset time that an oscillator generates. This time can be used in the equation to calculate the total reset time, at the given frequency. This time may vary slightly due to the initial start-up characteristics of the crystal/oscillator circuit.

Note 1: The rise time specification does not ensure that a valid V_{DD} operating voltage will be reached before the device exits reset. The device's V_{DD} must be within the specified operating range for proper device operation.

Note 2: The start-up characteristics of the crystal/oscillator must also be taken into account when determining the time that the device must be held in reset.

TABLE 5: MAXIMUM TIME FROM POR RISING EDGE TO VALID V_{DD} VOLTAGE

	Osc Mode	Maximum Time	Conditions
PIC16C5X	LP, XT, HS, and RC	9 ms	
PIC16CXXX	RC	28 ms	
	LP, XT, and HS	28 ms + 1024 T_{Osc}	PWRTE = 1
PIC16CXXX	LP, XT, and HS	1024 T_{Osc}	PWRTE = 0
PIC17CXXX	LF, XT, EC, and RC	Greater of (40 ms or 1024 T_{Osc})	

FIGURE 9: POR DELAY FOR FAST V_{DD} RISE TIME

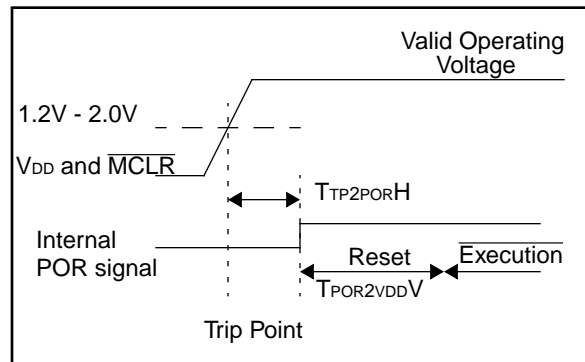


TABLE 6: RESET TIME DUE TO OSCILLATOR

	Clock Frequency								
	32 kHz	1 MHz	2 MHz	4 MHz	8 MHz	10 MHz	16 MHz	20 MHz	25 MHz
1024 T_{Osc}	32 ms	1.0 ms	512 μs	256 μs	128 μs	102.4 μs	64 μs	51.2 μs	41 μs

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FIGURE 10: MAXIMUM POWER-UP TIME, $\overline{\text{MCLR}}$ TIED TO V_{DD} (PIC16C5X, PIC16CXXX, PIC17CXXX)

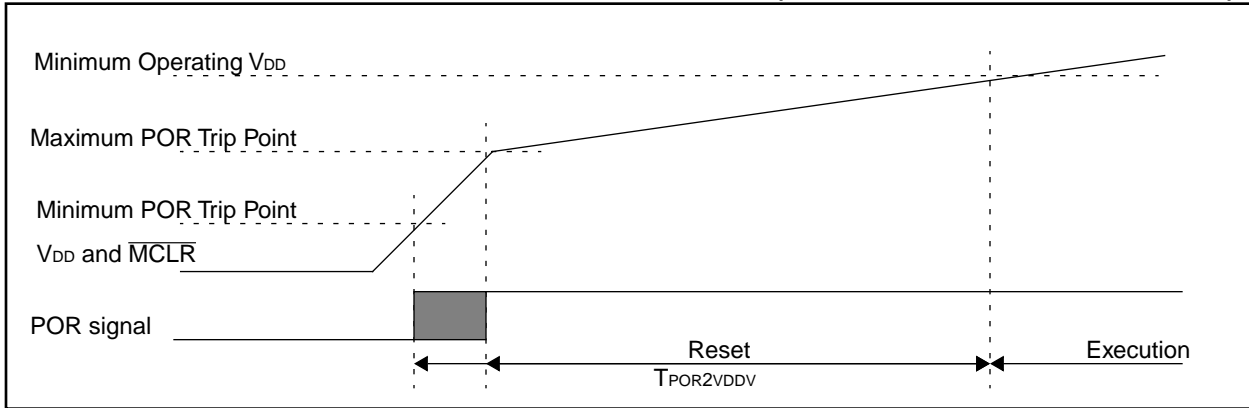


FIGURE 11: MAXIMUM POWER-UP TIME, $\overline{\text{MCLR}}$ NOT TIED TO V_{DD} (PIC16CXXX)

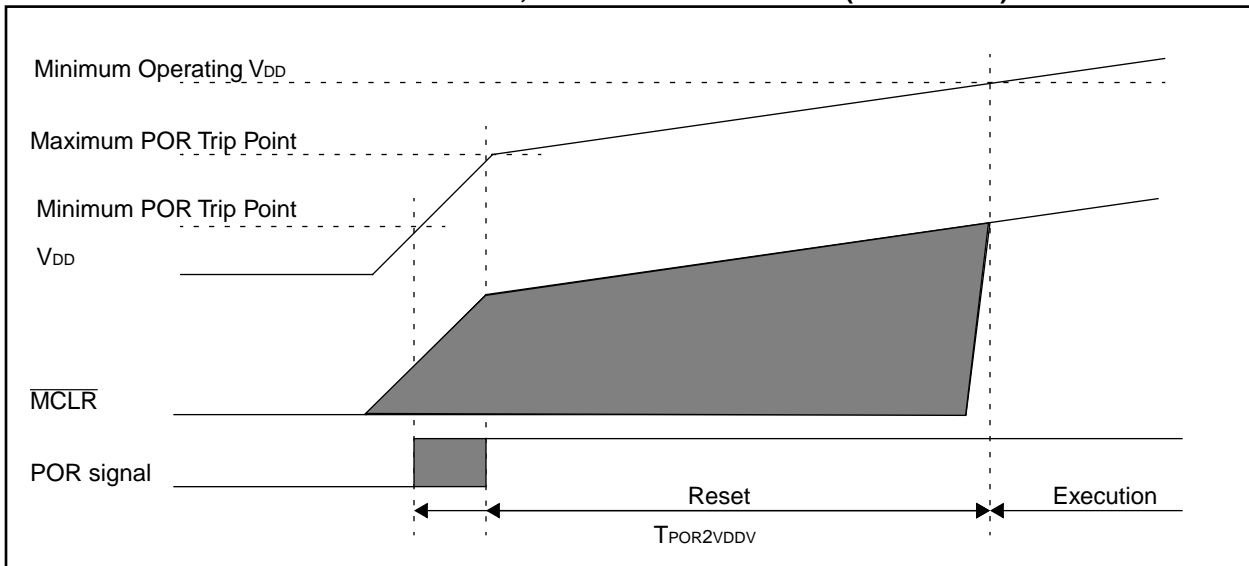
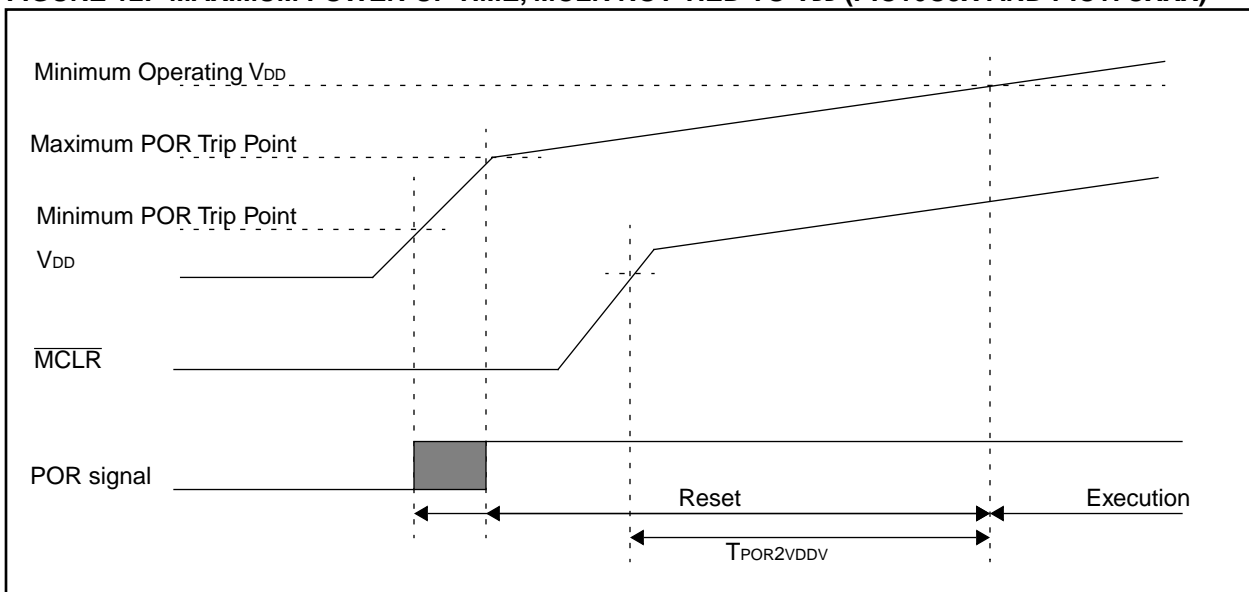


FIGURE 12: MAXIMUM POWER-UP TIME, $\overline{\text{MCLR}}$ NOT TIED TO V_{DD} (PIC16C5X AND PIC17CXXX)



Oscillator and Resonator Considerations

Oscillators and resonators from different manufacturers may have different characteristics. The recommended capacitor selection can be found in each device's data sheet. When we do the capacitor selection, during the oscillator/resonator characterization, we are currently using devices from one of several manufacturers. Generally we use oscillators from either ECS, CTS, FOX or Epson, and ceramic resonators from either Murata Erie or Panasonic. Other manufacturers may be used in the future, depending on availability and other factors.

Other manufacturers devices may have significantly different characteristics. To ensure proper oscillator operation, the circuit should be verified at the lowest temperature/highest V_{DD} (to ensure that the crystal is not overdriven), and with the highest temperature/lowest V_{DD} (to ensure the device still starts up) that the device will be subjected to while in the application. This ensures a stable start-up and frequency for this device, at the extreme conditions of the application.

For production purposes, the above testing should be done with many different samples of the components selected. This is so the part to part variation of the capacitors, resistors, crystals/resonators, and PICmicro devices are taken into account. All PICmicro final data sheets supply the characterization information on the transconductance of the oscillator (measurement of gain). This information can be used to check part to part variations of the PICmicro.

When selecting the crystal, the designer must ensure that it is a parallel cut type. Failure to use a parallel cut crystal may cause:

- Frequency operation out of the specified range of the crystal.
- Unreliable oscillator start-up.
- Device or crystal damage.

RAM and Special Function Register Initialization

After a successful Power-up Reset, the device will begin to execute the firmware program. To have expected operation, ALL RAM should be initialized by the program. This includes the Special Function Registers (SFR) and the general purpose data memory. The use (read) of an uninitialized RAM location will cause the program to do exactly what you told it, with the unexpected RAM value. It should not be expected that all devices will power-up with the same uninitialized device values.

There are many factors that contribute to how a RAM cell powers up, but the most common "gotcha" is between the Windowed and OTP device types. Many times a user forgets to cover the window after erasing the Windowed device. When the device is powering up, and the light is able to shine onto the device die, the transistor characteristics will shift. This can cause the

device RAM to have a different power-up value than a device where no light can shine onto the die (OTP or covered).

Note: RAM locations should be initialized before they are used. Use of an uninitialized location will cause proper device operation with the improper values. That is, it will do what you told it to do, not what you wanted it to do.

Valid Operating Voltage Levels

When the device is operating, the device voltage must be within the specified Min/Max limits. Operation of the device outside these limits may cause unexpected device operation.

One of the primary functional failure modes of a device is when the applied voltage is lower than the specified minimum requirement. This functional failure is called Brown-out. Brown-out causes the program memory not to be read correctly. For example, the program counter may be pointing to a MOVE instruction, but the device reads it as a GOTO instruction (with a random destination). This can have disastrous affects to the operation of the application. If brown-out conditions are possible, the application needs to be protected by using a brown-out circuit. A brown-out circuit works with the \overline{MCLR} pin to put the device in RESET before the device's actual voltage violates the minimum limit.

Figure 13 shows a low cost external brown-out protection circuit. The voltage at which the circuit causes a reset is dependent upon the tolerances of the components. Figure 14 shows the use of a Dallas Semiconductor EconoReset. This device monitors the status of the power supply, and generates a reset when an out-of-tolerance condition is detected. Motorola also makes some 3-terminal devices to monitor the power supply, such as the MC34164, MC34064, MC33064. Their data sheets should be reviewed to ensure that the device is suitable for your application.

FIGURE 13: LOW COST EXTERNAL BROWN-OUT PROTECTION CIRCUIT

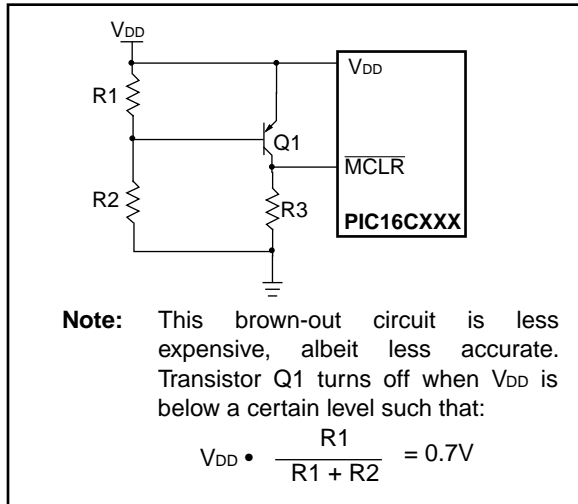
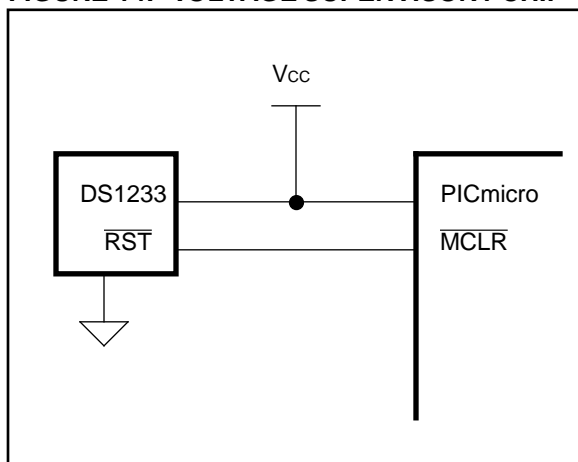


FIGURE 14: VOLTAGE SUPERVISORY CHIP



Brown-out and the WDT

The recommended solution for brown-out conditions is the use of a brown-out circuit. The brown-out circuit will keep the device in reset until a valid operating voltage is present. In some applications the additional cost of the external brown-out circuit, can be traded-off with system recovery from brown-out. Use of the Watchdog Timer (WDT) can enhance the probability of system recovery from a brown-out condition.

Note: If I/O drive conflicts can cause critical problems, this technique should not be used. This is due to the indeterminate time before a device reset could occur, which would reset all pins to inputs to eliminate any I/O conflict.

When using the WDT in brown-out conditions, care must be taken. Brown-outs may cause an unrecoverable condition, but with good design practice the probability of this can be significantly reduced.

During a brown-out, improper program execution can occur due to an EPROM read failure. This program execution can also corrupt data memory locations, which include the Special Function Registers (SFRs). Corrupting the control registers may cause hardware conflicts. For example, an input may become an output. Other conflicts are possible, but the situation will be application dependent.

As the device voltage gets lower, internal logic can become corrupted. This can include the Program Counter (PC) value, Stack Pointer and contents, State machines, Data Memory, etc.

When a valid voltage is returned, the device may be at an unexpected program location, possibly using corrupted values. In this situation, the device would not be expected to operate as intended and could get into a state that appears locked-up.

For the PIC17C42 in code protected microcontroller mode, once the Program Counter (PC) exceeds the 32K-word boundary, the device will become locked-up. The PC can exceed the 32K-word boundary from the execution of incorrect instructions (due to failure reading the EPROM) or by the PC becoming corrupted.

If the WDT is to be used to reset the device, care must be used in structuring the program. Optimally, only one CLRWDT instruction should be used. This minimizes the possibility of program execution returning to a loop which clears the WDT. This loop could then lock-up the device, since other control registers are corrupted and the device is not configured as expected. An example is; if the loop was waiting for an interrupt, but the bit that enables global interrupts was disabled, the device would no longer respond to the interrupts and would appear locked-up.

Example 1 shows a simple implementation of using the WDT reset for system recovery. The program loops, waiting for a WDT time-out (which clears the \overline{TO} bit). After the WDT reset, the \overline{TO} bit needs to be set (by executing a CLRWDT instruction). The program should then initialize the device. Then application code can start executing. There is a possibility of the \overline{TO} bit being corrupted by low voltage, and the device not being in a reset state when the software initializes the device.

The WDT example in Appendix B: uses a different method, independent of the \overline{TO} bit. This uses RAM locations which get loaded with a value. A WDT time-out (or other reset) needs to occur. The RAM locations are verified to contain the same values. Once the RAM is verified, it is cleared, and the device should be initialized. These RAM locations can be used by the application program.

EXAMPLE 1: USING WDT RESET

```

org   Reset_Address
      GOTO   TO_TEST      ;At any reset,
                          ;test the  $\overline{TO}$  bit

org   TO_TEST
      BTFSZ  STATUS, TO  ;WDT Time-Out?
      HERE  GOTO  HERE    ;NO, Wait for  $\overline{TO}$ 
Time_Out
      Time_Out ;YES, Good Reset
      CLRWDT ;Start here
      :      ;Initialize Device
      :      ;Application Code
    
```

False Power-down

In applications where power is removed from the device's supply lines, but voltage is still applied to an I/O pin, unexpected operation may occur. Power is able to be supplied to the device through this I/O pin. Since the device is still partially powered, the internal logic is never completely powered down. Figure 15 shows the general structure of an I/O pin. Figure 16 depicts the internal voltage level that is actually applied to some device logic, versus what is seen at the pin.

To guarantee a Power-on Reset (POR) rising edge, the device voltage (V_{DD}) must start from V_{SS} . When the device is inadvertently powered from an I/O pin, the voltage at the V_{DD} pin may appear to be near ground but may actually be higher in the device. With some of the internal logic powered, the characteristics of the device can be similar to a brown-out situation. Similar design practices to brown-out should be implemented.

A method for protecting the device from being powered from an I/O pin is shown in Figure 17.

FIGURE 15: TYPICAL ELECTRICAL STRUCTURE OF I/O PIN

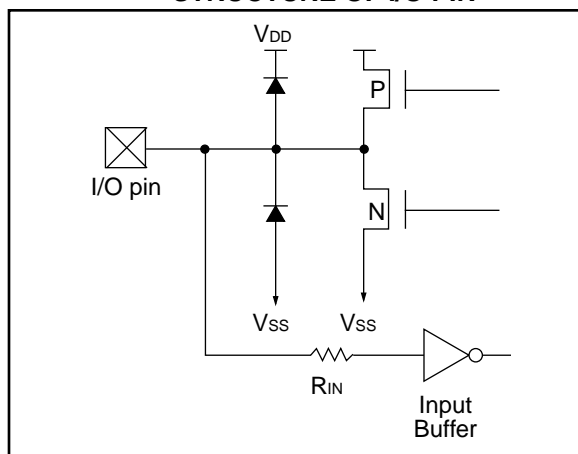


FIGURE 16: FALSE POWER-DOWN

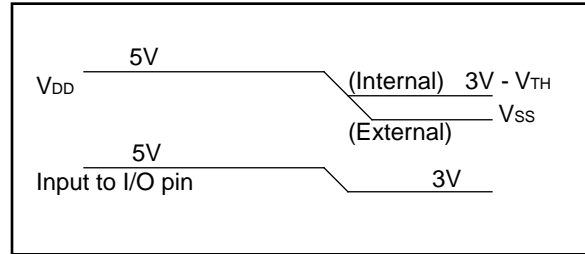
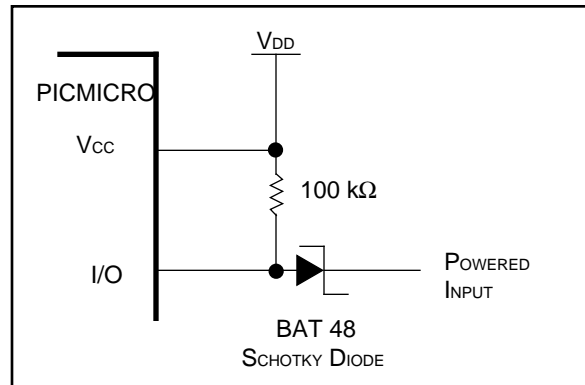


FIGURE 17: POWERED INPUT PROTECTION



In general, a brown-out detect circuit should cause the PICmicro to RESET (\overline{MCLR} forced low). This ensures that the internal logic is in a known state until a valid device voltage level is reached. The actual brown-out circuit depends on the voltage range of the device and the application requirements. A comprehensive brown-out circuit would use a dedicated device to monitor the voltage and force the \overline{MCLR} pin low when the voltage becomes lower than specified.

Another case of false power-down situations is when the power is removed from the system, but the capacitor loading keeps a non-zero voltage on the V_{DD} pin. When power is reapplied, the device never powered down so no Power-on-Reset will occur. A simple brown-out circuit should fix this.

TROUBLESHOOTING

There are several techniques that can be used to troubleshoot problems related to powering up. First it is important to try to locate the source of the problem. These sources could be:

- No oscillation on OSC1/OSC2 pins
- Improper/no Program Execution

In cases where there is no oscillation on the OSC1/OSC2 pins, some of the following should be tried:

- a) Verify that there are good connections/the components are good.
- b) Verify that the crystal/resonator manufacturer is one that has been tested, if not try other capacitor values.
- c) See if an external clock (from a function generator) causes device operation to begin.
- d) Verify that all components are well grounded.
- e) If a scope probe is connected to the oscillator output, it must be a low capacitance/high impedance probe. If it is not, the oscillator may stop.

In cases where program execution is not as expected:

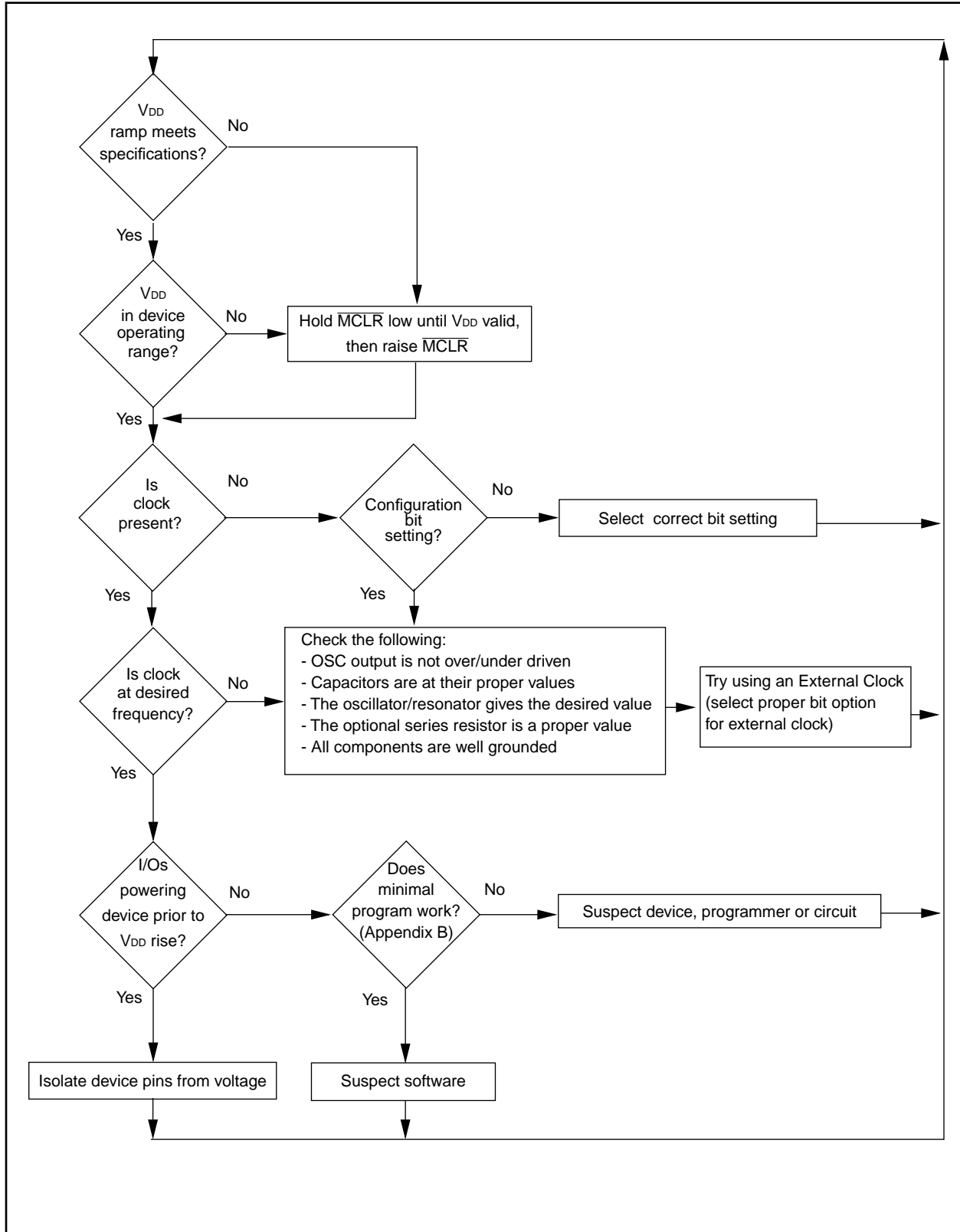
- a) Use a minimal program with external clock input.
- b) Tie \overline{MCLR} to ground until solid power is applied to the device then release \overline{MCLR} (bring high).
- c) Measure V_{DD} rise time to determine if an external reset circuit is needed, and, if so, what type of reset circuit should be used.
- d) Verify that the device program memory and configuration bits are programmed to their expected states.

The flowchart shown in Figure 18 can be used to troubleshoot power-up problems. This flowchart is only intended to be the first level diagnostic in trying to solve a power-up problem. Many other flowcharts can be used, depending on the characteristics of the problem and the set-up of the application.

CONCLUSION

Understanding the criteria for the powering up of a device will allow you to make better design choices. If device power-up problems are still encountered, many techniques can be used to solve the problem. Appendix B contains example code which can be used to verify that a device is operating (powered-up correctly). This eliminates the possibility of the program as the cause, and allows debug on the hardware.

FIGURE 18: TROUBLESHOOTING FLOWCHART



APPENDIX A: Q & As

Q. ***When I use a windowed device (JW), my application works as expected. When I program an OTP device, it no longer works as expected. Why is this?***

A. The silicon is the same between the OTP and windowed devices. If the windowed device's window is not covered (with black tape), light shines onto the silicon. The light causes the potential levels of gates to shift. This in turn can cause RAM to be initialized to an unknown state, which could be different than in the OTP device. If RAM is not initialized by the program before it is used, these different power-up states of the RAM could be the cause of the problem. Ensure that all RAM is initialized in the device. This includes the SFRs.

Q. ***My oscillator is not oscillating, what could be wrong?***

A. There are several possibilities, some which include:

1. The wrong oscillator bit setting is selected. The erased (default) state is RC oscillator mode.
2. The wrong capacitor values are installed. Refer to the most current data sheet for recommended values.
3. The characteristics of your manufacturers crystal are different than those that are characterized by Microchip. Generally our tests have been done with one of the following manufacturers' crystals/resonators: ECS, FOX, Murata Erie, or Panasonic.
4. The external connections to the device are wrong. Verify that all connections to the device are correct and that good signals / levels are being applied.
5. The cut of the crystal is a series type, as opposed to the specified parallel type.
6. No bypassing capacitors were used on the device. The noise on V_{DD} could be affecting the oscillator circuitry.

Q. ***The device was powered-down and then powered back up, but the device does not operate. What could be wrong.***

A. Possibilities include:

1. If power was applied to an I/O pin when the device was "powered-down", the device would be powered through the I/O pin. The internal logic is not actually powered-down, and Power-on Reset (POR) will not occur.
2. When V_{DD} was powered-down, V_{DD} was not given enough time to settle to 0V.
3. The V_{DD} ramp rate is too slow.

Q. ***My oscillator is oscillating, but the device is not working. What could be wrong?***

A. There are several possibilities, some which include:

1. Slow V_{DD} rise time, which was too slow to cause a Power-on Reset (POR). The rise time should not exceed the minimum device specification. For most devices this is 0.05 V/ms. Also the device must be at the minimum operating V_{DD} of the processor when reset is exited.
2. Ensure that the \overline{MCLR} pin is not low. This holds the device in RESET.
3. A brown-out has occurred, and has corrupted the internal state machines (including the WDT). An external brown-out circuit is recommended to hold the device in RESET during the brown-out condition.
4. The $CLRWDT$ instruction is not being used (often enough) when the WDT is enabled.

Q. ***When I power-up the device, it does not operate and it gets hot.***

A. Your design is probably permitting fast high voltage signals (spike) onto one of the device pins. This sudden high voltage (and associated current) is in excess of the protection diode limit. The device must be powered-down (to V_{SS}) to release this condition. This condition may cause a functional failure or affect device reliability. All Microchip devices meet or exceed the Human Body Model (HBM) and Machine Model (MM) for ESD and latch-up.

Q. ***My oscillator is oscillating, but not at the expected frequency. What could be wrong.***

A. For many designers, working with oscillators and their related issues are a “black magic”, since the characteristics can vary widely between manufacturers. I suggest that you read all the application notes that we have available on oscillators. Some quick possibilities are:

1. The cut of the crystal is a series type, as opposed to the specified parallel type.
2. No bypassing capacitors were used on the device. The noise on V_{DD} could affect the oscillator circuitry.
3. The capacitor values used are causing the oscillator to operate in one of the harmonic frequencies.

Note: This is not an all inclusive list. You may need to investigate other design aspects.

Q. ***The device seems to never exit reset, or is continually resetting.***

A. The `CLRWDT` instruction is not being used (often enough) when the WDT is enabled.

Q. ***The device was powered-down and back up again, but it does not reset. It just starts operating immediately.***

A. Possibilities include:

1. If power was applied to an I/O pin when the device was “powered-down”, the device would be powered through the I/O pin. The internal logic is not actually powered-down, and a Power-on Reset (POR) will not occur.
2. When V_{DD} was powered down, V_{DD} was not given enough time to settle to 0V.

Q. ***The oscillator is operating (I check it with a scope), yet when I look at other pins the program is not executing. Why?***

A. One possible reason is that when the oscilloscope probe is placed on the OSC2 pin, the additional capacitance is enough to cause oscillation to start. Removing the capacitive load of the probe causes the oscillation to stop.

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Please check the Microchip BBS for the latest version of the source code. Microchip's Worldwide Web Address: www.microchip.com; Bulletin Board Support: MCHIPBBS using CompuServe® (CompuServe membership not required).

APPENDIX B: TEST PROGRAMS

PIC16C5X BIT TOGGLE

MPASM 01.02.04 Intermediate C5X_B0T.ASM 12-20-1994 9:25:7 PAGE 1

```
LOC OBJECT CODE      LINE SOURCE TEXT
VALUE

0001          LIST    P = 16C54, F = INHX8M, n = 66
0002 ;
0003 ;*****
0004 ;
0005 ; This program is a minimum program to toggle a single I/O port pin for the
0006 ; 16C5x family of devices. The only initialization is that of the data
0007 ; direction register (TRIS) of the I/O pin and the Toggling of the pin.
0008 ; The waveform will be 1 unit high and 3 units low.
0009 ;
0010 ;          Program:          C5X_B0T.ASM
0011 ;          Revision Date:    12-20-94
0012 ;
0013 ;*****
0014 ;
0015 ;
0016 ; HARDWARE SETUP
0017 ;          None
0018 ;
0019 ;
0020          INCLUDE <p16C5x.inc>
0021 ; P16C5X.INC Standard Header File, Version 0.1      Microchip Technology, Inc.
0022 ;
0023 ;
0024 ;*****
0025 ;*****          Start program here.
0026 ;*****
0027 ;
0000          0028 START                                ; POWER_ON Reset (Beginning of program)
0000 0063          0029          CLRWF          STATUS          ; Do initialization (Bank 0)
0001 0C00          0030          MOVLW          0x00          ; Specify value for PortB output latch
0002 0026          0031          MOVWF          PORTB          ;
0003 0C00          0032          MOVLW          0x00          ; Specify which PortB pins are inputs / outputs
0004 0006          0033          TRIS          PORTB          ;
0005          0034 ;
0005 0506          0035 lzz          BSF          PORTB, 0          ; B0 is High
0006 0406          0036          BCF          PORTB, 0          ; B0 is Low
0007 0A05          0037          GOTO          lzz          ; Loop
0038 ;
0039 ;
0040 ;
0041 ;
0042 ; Reset address. Determine type of RESET
0043 ;
0044          IFDEF          __16C54
001FF 0045 RESET_V          EQU          0x1FF
0046          ENDIF
0047 ;
0048          IFDEF          __16C54A
0049 RESET_V          EQU          0x1FF
0050          ENDIF
0051 ;
0052          IFDEF          __16C55
0053 RESET_V          EQU          0x1FF
0054          ENDIF
0055 ;
0056          IFDEF          __16C56
0057 RESET_V          EQU          0x3FF
0058          ENDIF
0059 ;
0060          IFDEF          __16C57
0061 RESET_V          EQU          0x7FF
0062          ENDIF
```

```

0063 ;
0064     IFDEF     __16C58A
0065 RESET_V     EQU     0x7FF
0066     ENDIF
0067 ;
01FE     0068 PROG_MEM_END     EQU     RESET_V - 1
0069 ;
0070 ;
0071     org     PROG_MEM_END     ; End of Program Memory
01FE 0BFE 0072 ERR_LP_1     GOTO     ERR_LP_1     ; If you get here your program was lost
0073 ;
0074     org     RESET_V     ; RESET vector location
01FF 0A00 0075 R_VECTOR     GOTO     START     ;
0076 ;
0077 ;
0078     end
0079
0080
0081

```

MEMORY USAGE MAP ('X' = Used, '-' = Unused)

```

0000 : XXXXXXXX-----
0040 : -----
0180 : -----
01C0 : -----XX

```

All other memory blocks unused.

```

Errors   : 0
Warnings : 0
Messages : 0

```

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PIC16CXXX BIT TOGGLE

MPASM 01.02.04 Intermediate CXX_B0T.ASM 12-20-1994 10:18:22

PAGE 1

```
LOC OBJECT CODE      LINE SOURCE TEXT
VALUE

0001          LIST    P = 16C74, F = INHX8M, n = 66
0002 ;
0003 ;*****
0004 ;
0005 ; This program is a minimum program to toggle a single I/O port pin for the
0006 ; 16Cxx family of devices. The only initialization is that of the data
0007 ; direction register (TRIS) of the I/O pin and the Toggling of the pin.
0008 ; The waveform will be 1 unit high and 3 units low.
0009 ;
0010 ;      Program:          CXX_B0T.ASM
0011 ;      Revision Date:   12-20-94
0012 ;
0013 ;*****
0014 ;
0015 ;
0016 ; HARDWARE SETUP
0017 ;      None
0018 ;
0019 ;
0020          INCLUDE <p16Cxx.inc>
0021 ; P16CXX.INC Standard Header File, Version 0.2      Microchip Technology, Inc.
0022 ;
0023 ;
3FF9          0022      __FUSES ( _CP_OFF & _WDT_OFF & _XT_OSC & _PWRTE_ON )
0023 ;
0024 ;*****
0025 ;*****      Start program here.
0026 ;*****
0027 ;
0000          0028 START                                ; POWER_ON Reset (Beginning of program)
0000 0183      0029          CLRWF STATUS                ; Do initialization (Bank 0)
0001 3000      0030          MOVLW 0x00                    ; Specify value for PortB output latch
0002 0086      0031          MOVWF PORTB                    ;
0003 1683      0032          BSF STATUS, RP0                ; Bank 1
0004 3000      0033          MOVLW 0x00                    ; Specify which PortB pins are inputs / outputs
0005 0086      0034          MOVWF TRISB                    ;
0006 1283      0035          BCF STATUS, RP0                ; Bank 0
0007          0036 ;
0007 1406      0037 lzz          BSF PORTB, 0                ; B0 is High
0008 1006      0038          BCF PORTB, 0                    ; B0 is Low
0009 2807      0039          GOTO lzz                        ; Loop
0040 ;
0041 ;
0042 ;
0043 ;
0044 ; End of Program Memory
0045 ;
0046          IFDEF __16C71
0047 PROG_MEM_END EQU 0x3FF
0048          ENDIF
0049 ;
0050          IFDEF __16C71A
0051 PROG_MEM_END EQU 0x3FF
0052          ENDIF
0053 ;
0054          IFDEF __16C73
0055 PROG_MEM_END EQU 0xFFF
0056          ENDIF
0057 ;
0058          IFDEF __16C74
0059 PROG_MEM_END EQU 0xFFF
0060          ENDIF
0061 ;
0062          IFDEF __16C61
0063 PROG_MEM_END EQU 0x3FF
0064          ENDIF
0065 ;
0066          IFDEF __16C63
0067 PROG_MEM_END EQU 0x7FF
0068          ENDIF
0069 ;
0070          IFDEF __16C64
```



```

0071 PROG_MEM_END EQU 0x7FF
0072 ENDIF
0073 ;
0074 IFDEF __16C65
0075 PROG_MEM_END EQU 0xFFF
0076 ENDIF
0077 ;
0078 IFDEF __16C84
0079 PROG_MEM_END EQU 0x3FF
0080 ENDIF
0081 ;
0082 IFDEF __16C84A
0083 PROG_MEM_END EQU 0x3FF
0084 ENDIF
0085 ;
0086 ;
0087 org PROG_MEM_END ; End of Program Memory
0088 ERR_LP_1 GOTO ERR_LP_1 ; If you get here your program was lost
0089 ;
0090 ;
0091 end
0092
0093
0094
0095

```

MEMORY USAGE MAP ('X' = Used, '-' = Unused)

```

0000 : XXXXXXXXXXXX-----
0040 : -----
0F80 : -----
0FC0 : -----X

```

All other memory blocks unused.

```

Errors : 0
Warnings : 0
Messages : 0

```

Note: Special Function Register data memory locations, in Bank 1, are specified by their true address in the file PIC16CXXX.INC. The use of the MPASM assembler will generate a warning message, when those labels are used with direct addressing. Warning messages can be turned off with an assembler option.

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PIC17CXXX BIT TOGGLE

MPASM 01.02.04 Intermediate P17_B0T.ASM 12-19-1994 17:15:3

PAGE 1

```
LOC OBJECT CODE      LINE SOURCE TEXT
VALUE

0001          LIST    P = 17C42, F = INHX32, n = 66
0002 ;
0003 ;*****
0004 ;
0005 ; This program is a minimum program to toggle a single I/O port pin for the
0006 ; 17Cxx family of devices. The only initialization is that of the data
0007 ; direction register (DDR) of the I/O pin and the Toggling of the pin.
0008 ; The waveform will be 1 unit high and 1 unit low.
0009 ;
0010 ;          Program:          P17_B0T.ASM
0011 ;          Revision Date:    12-20-94
0012 ;
0013 ;*****
0014 ;
0015 ;
0016 ; HARDWARE SETUP
0017 ;          None
0018 ;
0019 ;
0020          INCLUDE <p17Cxx.inc>
0002 ; P17CXX.INC Standard Header File, Version 0.2      Microchip Technology, Inc.
0020
0021 ;
FFE2          0022          __FUSES ( _MC_MODE & _WDT_NORM & _XT_OSC )
0023 ;
0024 ;*****
0025 ;****          Start program here.
0026 ;*****
0000          0027 ;
0000          0028 START                                ; POWER_ON Reset (Beginning of program)
0000 2904          0029          CLRF    ALUSTA          ; Do initialization
0001 290F          0030          CLRF    BSR            ; Bank 0
0002 B000          0031          MOVLW  0x00          ; Specify value for PortB output latch
0003 0112          0032          MOVWF  PORTB         ;
0004 B000          0033          MOVLW  0x00          ; Specify which PortB pins are inputs / outputs
0005 0111          0034          MOVWF  DDRB         ;
0006          0035 ;
0006 3812          0036 lzz          BTG      PORTB, 0    ; Toggle level on B0
0007 C006          0037          GOTO   lzz          ; Loop
0008          0038 ;
0009          0039 ;
0010          0040
0011          0041 ;
0012          0042 ; End of Program Memory
0013          0043 ;
0014          0044          IFDEF  __17C42
0015          0045 PROG_MEM_END EQU      0x7FF
0016          0046          ENDIF
0017          0047 ;
0018          0048 ;
0019          0049          org      PROG_MEM_END      ; End of Program Memory
0020          07FF C7FF          0050 ERR_LP_1 GOTO   ERR_LP_1      ; If you get here your program was lost
0021          0051 ;
0022          0052 ;
0023          0053          end
0024          0054
0025          0055
```

MEMORY USAGE MAP ('X' = Used, '-' = Unused)

```
0000 : XXXXXXXX-----
0040 : -----
0080 : -----
07C0 : -----X
```

All other memory blocks unused.

```
Errors      : 0
Warnings    : 0
Messages    : 0
```

WDT RESET WITH RAM VERIFY

MPASM 01.20 Released

BO_RAMT.ASM 6-30-1995 16:04:36

PAGE 1

```

LOC OBJECT CODE      LINE SOURCE TEXT
VALUE

00001          LIST    P = 17C44, F = INHX32, n = 66
00002 ;
00003 ;*****
00004 ;
00005 ; This program is a minimum program to recover from a brown-out condition thru
00006 ; the use of the WDT. The method is to load RAM locations with a known value
00007 ; and compare these locations after any RESET. If the RAM location matches the
00008 ; expected value then program flow can continue. The longer this RAM string
00009 ; is, the greater the probability that the RAM would NOT power up in that state.
00010 ;
00011 ;
00012 ; NOTE: This does not Guarantee device recovery, due to the random start-up
00013 ; point after brown-out. This point could be a loop with a CLRWDT
00014 ; instruction. The recommended solution is to always use a brown-out
00015 ; circuit.
00016 ;
00017 ; Program:          B0_RAMT.ASM
00018 ; Revision Date:   06-29-95
00019 ;
00020 ;*****
00021 ;
00022 ;
00023 ; HARDWARE SETUP
00024 ; None
00025 ;
00026 ;
0001 00027 TRUE      EQU    1
0000 00028 FALSE     EQU    0
00029 ;
0001 00030 Debug      EQU    TRUE
00031 #define     __CONFIG __FUSES
00032 ;
00033          INCLUDE <DEV_FAM.inc>
00102 list
00034 ;
00035 if ( P16C5X )
00036     INCLUDE <p16C5x.inc>
00037     __CONFIG ( _CP_OFF & _WDT_ON & _XT_OSC )
00038 endif
00039 ;
00040 if ( P16CXX )
00041     INCLUDE <p16Cxx.inc>
00042     __CONFIG ( _CP_OFF & _WDT_ON & _XT_OSC & _PWRT_ON )
00043 endif
00044 ;
00045 if ( P17CXX )
00046     INCLUDE <p17Cxx.inc>
00001 LIST
00002 ; P17CXX.INC Standard Header File, Version 2.01      Microchip Technology, Inc.
00298 LIST
FE00 FFE2 00047     __CONFIG ( _MC_MODE & _WDT_NORM & _XT_OSC )
00048     endif
00049 ;
00050 if ( P16C5X + P16CXX + P17CXX != 1 )
00051 MESSG "WARNING - USER DEFINED: One and only one device family can be selected"
00052     endif
00053 ;
00054          INCLUDE <BO_RAMT.inc>
00029 list
00055          INCLUDE <PMEM_END.inc>
00116 list
00056 ;
00057 ;
00058 ;*****
00059 ;**** Start program here.
00060 ;*****
00061 ;
0000 00062 org Reset_Address
00063 ; ; in the LIST directive
00064 if ( P16C5X )
00065     org 0h ; Override the start of this code.
00066     CLRF STATUS ; Force program memory to Page 0
00067     CLRF FSR ; Force Data Memory to Bank 0
00068     endif

```

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```
00069 ;
00070     if ( P16CXX )
00071         CLRF   PCLATH      ; Force program memory to Page 0
00072         CLRF   STATUS      ; Force Data Memory to Bank 0
00073     endif
00074 ;
00075     if ( P17CXX )
00076         CLRF   PCLATH, F   ; Force program memory to Page 0
0000 2903 00077         CLRF   BSR, F    ; Force Peripheral / GP Data Memory to Bank 0
0001 290F 00078     endif
00079 ;
0002 C100 00080         GOTO   RAM_TEST   ; At any reset,
00081         ; test the RAM
00082 ;
00083 ; In RAM_TEST, program execution is held-off until a valid "warm" reset
00084 ; occurs. That is, the contents of some RAM locations retain the
00085 ; values that were written to them. The probability that the RAM would power-up
00086 ; in that state is dependent on the number of bytes of RAM used. The
00087 ; more RAM, the less the probability (probability = 1 / ( 2 ** 8(N+1) ).
00088 ;
00089 ;
0100      00090     org   MAIN           ; In Program Memory Page 0
0100      00091     RAM_TEST
0100 B0A5 00092         MOVLW  BYTE_0
0101 0520 00093         SUBWF  RAM0, F
0102 9204 00094         BTFSS  STATUS, Z    ; Result = 0?
0103 C110 00095         GOTO   LD_RAM      ; NO, Load Ram
00096 ;
0104 B00F 00097         MOVLW  BYTE_1      ; YES, Check next
0105 0521 00098         SUBWF  RAM1, F    ; location
0106 9204 00099         BTFSS  STATUS, Z    ; Result = 0?
0107 C110 00100         GOTO   LD_RAM      ; NO, Load RAM
00101 ;
00102 ;         :                   ; YES, Do Again
00103 ;         :                   ;
00104 ;
0108 B05A 00105         MOVLW  BYTE_n      ; YES, Check nth
0109 0522 00106         SUBWF  RAMn, F    ; location
010A 9204 00107         BTFSS  STATUS, Z    ; Result = 0?
010B C110 00108         GOTO   LD_RAM      ; NO, Load RAM
00109 ;
00110     if ( P16C5X || P16CXX )
00111         CLRF   RAM0        ; YES, Time-out
00112         CLRF   RAM1        ; occurred, clear
00113 ;         :                   ; RAM locations
00114 ;         :                   ;
00115         CLRF   RAMn        ;
00116     endif
00117 ;
00118 ;
00119     if ( P17CXX )
010C 2920 00120         CLRF   RAM0, F    ; YES, Time-out
010D 2921 00121         CLRF   RAM1, F    ; occurred, clear
00122 ;         :                   ; RAM locations
00123 ;         :                   ;
00124         CLRF   RAMn, F    ;
010E 2922 00125     endif
00126 ;
010F C117 00127         GOTO   Time_Out   ; Initialize Device
00128 ;
0110      00129     LD_RAM
0110 B0A5 00130         MOVLW  BYTE_0      ; Load RAM
0111 0120 00131         MOVWF  RAM0        ; locations to
0112 B00F 00132         MOVLW  BYTE_1      ; compare against
0113 0121 00133         MOVWF  RAM1        ;
00134 ;         :                   ;
0114 B05A 00135         MOVLW  BYTE_n      ;
0115 0122 00136         MOVWF  RAMn        ;
00137 ;
0116 C116 00138     HERE   GOTO   HERE      ; Wait for WDT TO
0117      00139     Time_Out
0117 0004 00140         CLRWDT   ; Start here
00141 ;         :                   ; Initialize Device
00142 ;         :                   ; Application Code
00143 ;
00144     if ( Debug )           ;
00145         if ( P16C5X )
00146             CLRF   PORTB      ; PORTB output latch is cleared
00147             MOVLW  0x00      ;
00148             TRIS  PORTB      ; Port B is output
00149             BCF   PORTB, 0    ;
00150             BSF   PORTB, 0    ; Toggle pin B0
00151         endif
```

```

00152 ;
00153     if ( P16CXX )
00154         CLRF    PORTB        ; PORTB output latch is cleared
00155         BSF    STATUS, RP0   ; Bank 1
00156         CLRF    TRISB       ; Port B is output
00157         BCF    STATUS, RP0   ; Bank 0
00158         BCF    PORTB, 0      ;
00159         BSF    PORTB, 0      ; Toggle pin B0
00160     endif
00161 ;
00162     if ( P17CXX )
0118 2912 00163         CLRF    PORTB, F    ; PORTB output latch is cleared
0119 2911 00164         CLRF    DDRB, F    ; Port B is output
011A 8812 00165         BCF    PORTB, 0      ;
011B 8012 00166         BSF    PORTB, 0      ; Toggle pin B0
00167     endif
00168     endif
00169 ;
011C C117 00170         GOTO    Time_Out        ; Return to start of Program
00171 ;
1FFF     00172         org    PROG_MEM_END    ; End of Program Memory
1FFF     00173 ERR_LP_1
1FFF DFFF 00174         GOTO    ERR_LP_1        ; If you get here your program was lost
00175 ;
00176     if ( P16C5X )
00177         NOP
00178     ; This will cause the Program memory rollover
00179     ; for PIC16C5x devices
00179     endif
00180 ;
00181 ;
00182     end

```

MEMORY USAGE MAP ('X' = Used, '-' = Unused)

```

0000 : XXX-----
0040 : -----
0100 : XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXX-----
0140 : -----
1F80 : -----
1FC0 : -----X
FE00 : X-----
FE40 : -----

```

All other memory blocks unused.

```

Errors   : 0
Warnings : 0
Messages : 0

```



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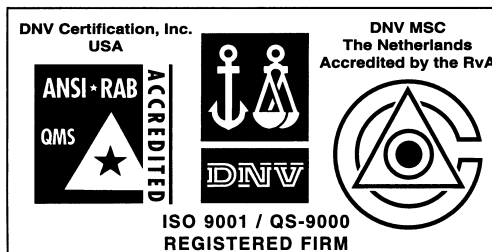
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